NSN 5962-01-388-0029

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Maximum Power Dissipation Rating:	
1.2 watts	
Operating Tempurature Range:	
-55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
-65.0/+150.0 degrees celsius	
End Application:	
Used on: cobra dane next assembly: g526534	
Features Provided:	
Electrostatic sensitive and programmed and tested	o mil-std-883
Inclosure Configuration:	
Dual-in-line	
Output Logic Form:	
Complementary-metal oxide-semiconductor logic	
Case Outline Source And Designator:	
D-9 mil-m-38510	
Terminal Surface Treatment:	
Solder	
Product Name:	
22-input 10-output and-or0logic array	
Voltage Rating And Type Per Characteristic:	
-0.5 volts applied and 7.0 volts applied	
Time Rating Per Chacteristic:	
25.00 nanoseconds access	
Memory Device Type:	
Pal	
Hybrid Technology Type:	
Monolithic	
Special Features:	
One-time programmable	
Test Data Document:	
81349-mil-m-38510 specification (includes engineer	ing type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry dire	ectories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and te	est conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:	
24 printed circuit	
Specification Data:	
67267-5962-8867001la government standard	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
Vaa damil/mli	

Yes - demil/mli

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